

JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

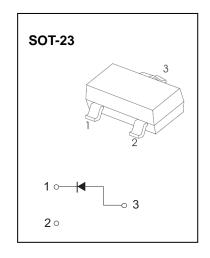
SOT-23 Plastic-Encapsulate Diodes

1SS187 Switching Diode

FEATURES

- Low forward voltage
- Fast reverse recovery time

MARKING: D3 •



Maximum Ratings @Ta=25℃

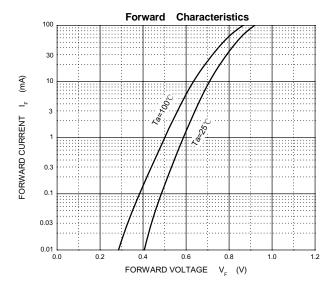
Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V_{RM}	85	V
DC Blocking Voltage	V _R	80	V
Forward Continuous Current	I _{FM}	300	mA
Average Rectified Output Current	I ₀	100	mA
Power Dissipation	P _D	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature range	T _{STG}	-55~+150	°C

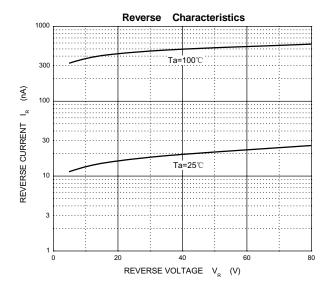
Electrical Characteristics @Ta=25℃

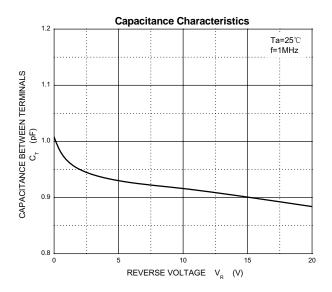
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Reverse breakdown voltage	V _(BR)	80			V	I _R =100μA
Forward voltage	V _{F1}		0.61		V	I _F =1mA
	V _{F2}		0.74		V	I _F =10mA
	V _{F3}		0.92	1.2	V	I _F =100mA
Reverse current	I _{R1}			0.1	uA	V _R =30V
	I _{R2}			0.5	uA	V _R =80V
Capacitance between terminals	C _T		2.2	4.0	pF	V _R =0,f=1MHz
Reverse recovery time	t _{rr}		1.6	4.0	ns	I _F =I _R =10mA,I _{rr} =0.1×I _R

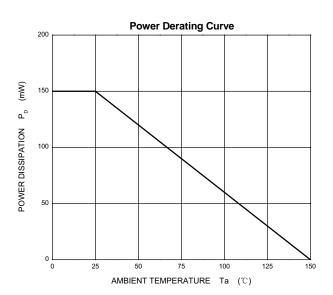
Typical Characteristics

1SS187









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